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# N-Channel NexFET™ Power MOSFET

Check for Samples: CSD16327Q3

#### **FEATURES**

- Optimized for 5V Gate Drive
- Ultra Low Qg and Qgd
- Low Thermal Resistance
- Avalanche Rated
- · Pb Free Terminal Plating
- RoHS Compliant
- · Halogen Free
- SON 3.3mm x 3.3mm Plastic Package

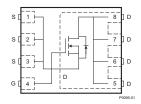
#### **APPLICATIONS**

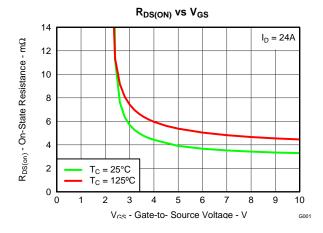
- Point-of-Load Synchronous Buck Converter for Applications in Networking, Telecom and Computing Systems
- Optimized for Control or Synchronous FET Applications

#### **DESCRIPTION**

The NexFET™ power MOSFET has been designed to minimize losses in power conversion and optimized for 5V gate drive applications.







#### PRODUCT SUMMARY

$V_{DS}$	Drain to Source Voltage	25	V	
$Q_g$	Gate Charge Total (4.5V) 6.2			
$Q_{gd}$	Gate Charge Gate to Drain 1.1			
		$V_{GS} = 3V$	5	mΩ
R <sub>DS(on)</sub>	Drain to Source On Resistance	V <sub>GS</sub> = 4.5V 4		
		V <sub>GS</sub> = 8V 3.4		
$V_{th}$	Threshold Voltage	1.2	V	

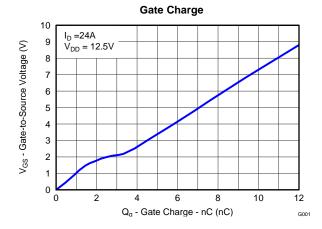
#### ORDERING INFORMATION

Device	Device Package			Ship
CSD16327Q3	SON 3.3 × 3.3 Plastic Package	13-inch reel	2500	Tape and Reel

#### **ABSOLUTE MAXIMUM RATINGS**

T <sub>A</sub> = 2	5°C unless otherwise stated	VALUE	UNIT
$V_{DS}$	Drain to Source Voltage	25	V
$V_{GS}$	Gate to Source Voltage	+10 / –8	٧
1	Continuous Drain Current, T <sub>C</sub> = 25°C	60	Α
I <sub>D</sub>	Continuous Drain Current <sup>(1)</sup>	21	Α
$I_{DM}$	Pulsed Drain Current, T <sub>A</sub> = 25°C <sup>(2)</sup>	112	Α
$P_D$	Power Dissipation <sup>(1)</sup>	3	W
T <sub>J</sub> , T <sub>STG</sub>	Operating Junction and Storage Temperature Range	-55 to 150	°C
E <sub>AS</sub>	Avalanche Energy, single pulse $I_D = 50A, L = 0.1 mH, R_G = 25\Omega$	125	mJ

- (1)  $R_{\theta JA} = 45^{\circ}\text{C/W}$  on  $1\text{in}^2$  Cu (2 oz.) on 0.060" thick FR4 PCB.
- (2) Pulse width ≤300µs, duty cycle ≤2%



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

#### **ELECTRICAL CHARACTERISTICS**

(T<sub>A</sub> = 25°C unless otherwise stated)

	PARAMETER	TEST CONDITIONS	MIN TYP	MAX	UNIT
Static Cl	naracteristics				
BV <sub>DSS</sub>	Drain to Source Voltage	$V_{GS} = 0V, I_D = 250\mu A$	25		V
I <sub>DSS</sub>	Drain to Source Leakage Current	V <sub>GS</sub> = 0V, V <sub>DS</sub> = 20V		1	μΑ
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{DS} = 0V, V_{GS} = +10/-8V$		100	nA
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	0.9 1.2	1.4	V
		$V_{GS} = 3V, I_D = 24A$	5	6.5	mΩ
R <sub>DS(on)</sub>	Drain to Source On Resistance	$V_{GS} = 4.5V, I_D = 24A$	4	4.8	
		$V_{GS} = 8V, I_D = 24A$	3.4	4	
g <sub>fs</sub>	Transconductance	V <sub>DS</sub> = 12.5V, I <sub>D</sub> = 24A	96		S
Dynamic	: Characteristics			*	
C <sub>ISS</sub>	Input Capacitance		1020	1300	pF
Coss	Output Capacitance	V <sub>GS</sub> = 0V, V <sub>DS</sub> = 12.5V, f = 1MHz	740	960	pF
C <sub>RSS</sub>	Reverse Transfer Capacitance		50	65	pF
Rg	Series Gate Resistance		1.4	2.8	Ω
Qg	Gate Charge Total (4.5V)		6.2	8.4	nC
$Q_{gd}$	Gate Charge Gate to Drain		1.1		nC
Q <sub>gs</sub>	Gate Charge Gate to Source	$V_{DS} = 12.5V, I_{D} = 24A$	1.8		nC
Qg(th)	Gate Charge at Vth		1		nC
Q <sub>OSS</sub>	Output Charge	V <sub>DS</sub> = 12.5V, V <sub>GS</sub> = 0V	14		nC
t <sub>d(on)</sub>	Turn On Delay Time		5.3		ns
t <sub>r</sub>	Rise Time	$V_{DS} = 12.5V, V_{GS} = 4.5V I_{D} = 24A$	15		ns
t <sub>d(off)</sub>	Turn Off Delay Time	$R_G = 2\Omega$	13		ns
t <sub>f</sub>	Fall Time		6.3		ns
Diode Cl	haracteristics			"	
V <sub>SD</sub>	Diode Forward Voltage	$I_S = 24A, V_{GS} = 0V$	0.85	1	V
Q <sub>rr</sub>	Reverse Recovery Charge	$V_{DD} = 12.5V$ , $I_F = 24A$ , $di/dt = 300A/\mu s$	21		nC
t <sub>rr</sub>	Reverse Recovery Time	$V_{DD} = 12.5V$ , $I_F = 24A$ , $di/dt = 300A/\mu s$	16		ns

#### THERMAL CHARACTERISTICS

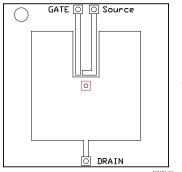
 $(T_{\Delta} = 25^{\circ}C \text{ unless otherwise stated})$ 

( · A –					
	PARAMETER	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Thermal Resistance Junction to Case <sup>(1)</sup>			1.7	°C/W
R <sub>A.IA</sub>	Thermal Resistance Junction to Ambient <sup>(1)(2)</sup>			56	°C/W

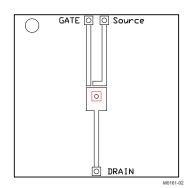
<sup>(1)</sup> RqJC is determined with the device mounted on a 1-inch2 (6.45-cm2), Cu pad on a 1.5-inch × 1.5-inch thick FR4 PCB. RqJC is specified by design, whereas RqJA is determined by the user's board design.

<sup>(2)</sup> Device mounted on FR4 material with 1-inch2 2-oz.Cu.

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Max  $R_{\theta JA} = 56^{\circ} C/W$  when mounted on 1 inch<sup>2</sup> of 2 oz. Cu.



Max  $R_{\theta JA} = 179^{\circ} C/W$  when mounted on minimum pad area of 2 oz. Cu.

#### TYPICAL MOSFET CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 

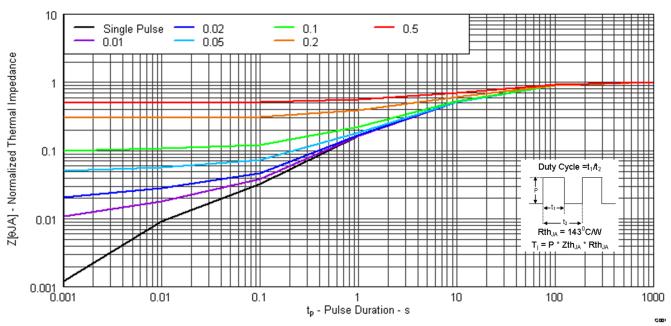


Figure 1. Transient Thermal Impedance

# **ISTRUMENTS**

# **TYPICAL MOSFET CHARACTERISTICS (continued)**

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 

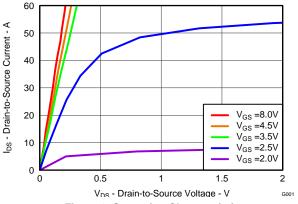


Figure 2. Saturation Characteristics

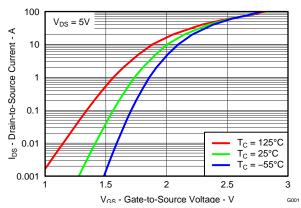


Figure 3. Transfer Characteristics

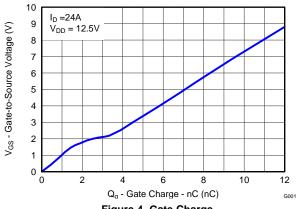


Figure 4. Gate Charge

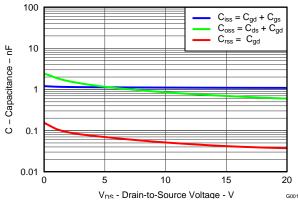


Figure 5. Capacitance

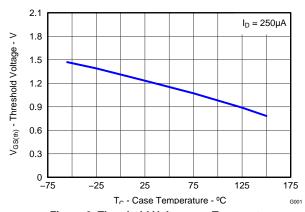


Figure 6. Threshold Voltage vs. Temperature

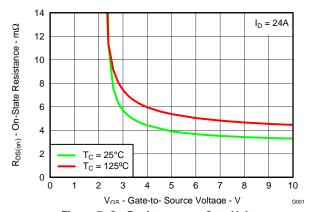


Figure 7. On Resistance vs. Gate Voltage

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## TYPICAL MOSFET CHARACTERISTICS (continued)

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 

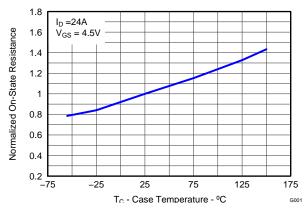


Figure 8. Normalized On Resistance vs. Temperature

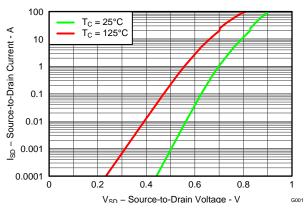


Figure 9. Typical Diode Forward Voltage

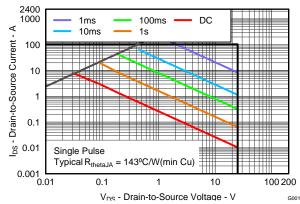


Figure 10. Maximum Safe Operating Area

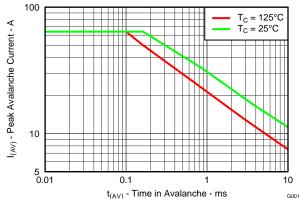
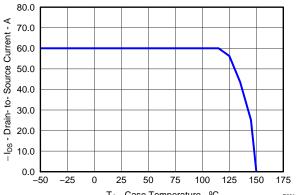


Figure 11. Single Pulse Unclamped Inductive Switching

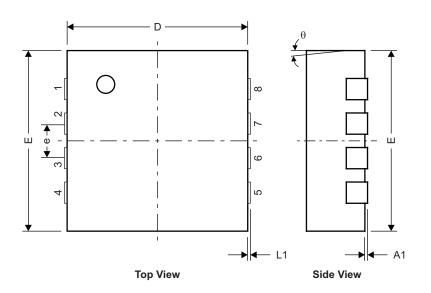


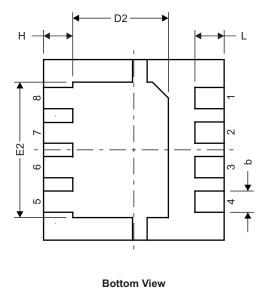
 $$T_{\rm C}$$  - Case Temperature -  ${}^{\rm QC}$  Figure 12. Maximum Drain Current vs. Temperature

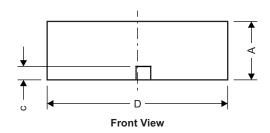


## **MECHANICAL DATA**

# **Q3 Package Dimensions**





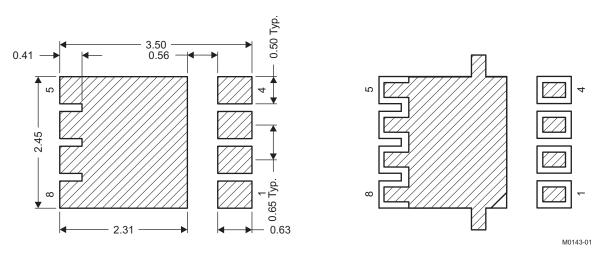


M0142-01

DIM	l	MILLIMETERS	3	INCHES			
	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.950	1.000	1.100	0.037	0.039	0.043	
A1	0.000	0.000	0.050	0.000	0.000	0.002	
b	0.280	0.340	0.400	0.011	0.013	0.016	
С	0.150	0.200	0.250	0.006	0.008	0.010	
D	3.200	3.300	3.400	0.126	0.130	0.134	
D1	_	-	-	_	_	_	
D2	1.650	1.750	1.800	0.065	0.069	0.071	
E	3.200	3.300	3.400	0.126	0.130	0.134	
E1	_	-	-	_	-	_	
E2	2.350	2.450	2.550	0.093	0.096	0.100	
е	e 0.650 TYP 0.026						
Н	0.35	0.450	0.550	0.014	0.018	0.022	
L	0.35	0.450	0.550	0.014	0.018	0.022	
L1	_	_	-	_	_	_	
θ	-	-	-	_	-	_	

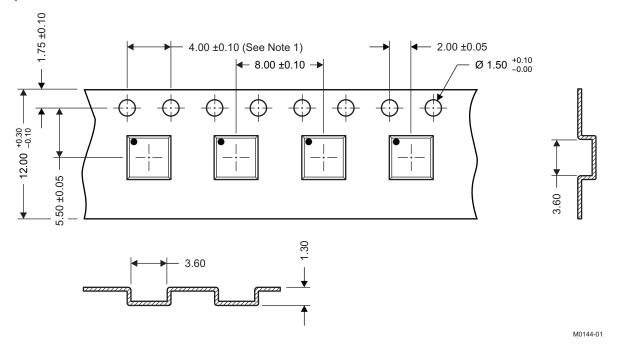
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#### **Recommended PCB Pattern**



For recommended circuit layout for PCB designs, see application note SLPA005 – Reducing Ringing Through PCB Layout Techniques.

## **Q3 Tape and Reel Information**



#### Notes:

- 1. 10 sprocket hole pitch cumulative tolerance ±0.2
- 2. Camber not to exceed 1mm IN 100mm, noncumulative over 250mm
- 3. Material:black static dissipative polystyrene
- 4. All dimensions are in mm (unless otherwise specified)
- 5. Thickness: 0.30 ±0.05mm
- 6. MSL1 260°C (IR and Convection) PbF Reflow Compatible



# PACKAGE OPTION ADDENDUM

28-Dec-2011

#### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/ Ball Finish	MSL Peak Temp <sup>(3)</sup>	Samples (Requires Login)
CSD16327Q3	ACTIVE	SON	DQG	8	2500	Pb-Free (RoHS Exempt)	CU SN	Level-1-260C-UNLIM	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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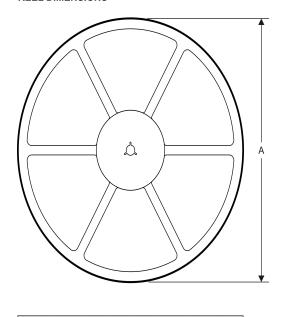
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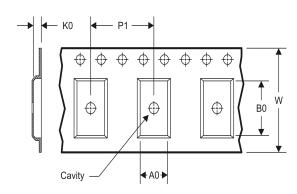
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## TAPE AND REEL INFORMATION

#### **REEL DIMENSIONS**



#### **TAPE DIMENSIONS**



A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

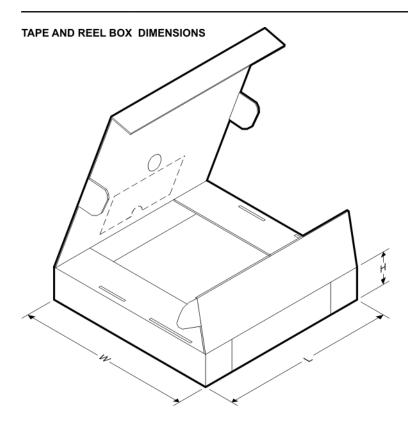
#### TAPE AND REEL INFORMATION

#### \*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CSD16327Q3	SON	DQG	8	2500	330.0	12.8	3.6	3.6	1.2	8.0	12.0	Q1

**PACKAGE MATERIALS INFORMATION** 

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#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CSD16327Q3	SON	DQG	8	2500	335.0	335.0	32.0

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